

Notice of References Cited

Application/Control No.

09/807,515

Applicant(s)/Patent Under
Reexamination
HERBERT ET AL.

Examiner

Donghee Kang

Art Unit

2811

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
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FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	J.K.Mishra et al., "Design Optimization of a single-sided Si ⁺ /SiGe heterostructure mixed tunneling avalanche transistor double drift region", Semiconductor Sci. Tech. 12 (1997) 1635-1640.
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